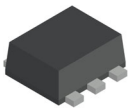
Monolithic Microwave Integrated Circuits (MMIC)

Amplifier, 3 V, 6 mA, 0.1 to 2.8 GHz, MCPH6

SMA3107

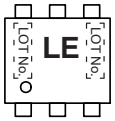


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Features

- High Gain : G_p = 23.5 dB typ. @1 GHz
- Wideband Response : f_u = 2.8 GHz
- Low Current : I_{CC} = 6 mA typ
- Port Impedance : Input/Output 50 Ω
- This is a Pb−Free Device

MARKING DIAGRAM



LE = Specific Device Code

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Symbol	Parameter	Ratings	Unit
V_{CC}	Supply Voltage	5	V
I_{CC}	Circuit Current	15	mA
P_D	Allowable Power Dissipation	280	mW
T_{opr}	Operating Temperature	−40 to +85	°C
T_{STG}	Storage Temperature	−55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITION

(T_A = 25°C unless otherwise noted)

Symbol	Parameter	Ratings			Unit
		Min	Typ	Max	
V_{CC}	Supply Voltage	2.7	3	3.3	V
T_{opr}	Operating Ambient Temperature	−40	+25	+85	°C

ORDERING INFORMATION

Device	Package	Shipping†
SMA3107−TL−E	MCPH6 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C, V_{CC} = 3 V, Z_s = Z_L = 50 Ω)

Symbol	Parameter	Conditions	Ratings			Unit
			Min	Typ	Max	
I_{CC}	Circuit Current		4.3	6.0	7.7	mA
G_p	Power Gain	f = 1 GHz	21.0	23.5	26.0	dB
		f = 2.2 GHz	22.0	24.5	27.0	
I_{SL}	Isolation	f = 1 GHz	33.0	38.0	–	dB
		f = 2.2 GHz	40.0	45.0	–	dB
R_{Lin}	Input Return Loss	f = 1 GHz	18.0	23.0	–	dB
		f = 2.2 GHz	10.0	13.0	–	
R_{Lout}	Output Return Loss	f = 1 GHz	27.0	32.0	–	dB
		f = 2.2 GHz	10.0	13.0	–	dB
NF	Noise Figure	f = 1 GHz	–	3.1	4.3	dB
		f = 2.2 GHz	–	3.6	4.3	
$P_{o(1dB)}$	Gain 1 dB Compression Output Power	f = 1 GHz	−10	−8	–	dBm
		f = 2.2 GHz	−11.5	−9.5	–	
f_u	Upper Limit Operating Frequency	3 dB down below fl at gain at f = 1 GHz	–	2.8	–	GHz

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

NOTES: Pay attention to handling since it is liable to be affected by static electricity due to the high frequency process adopted.

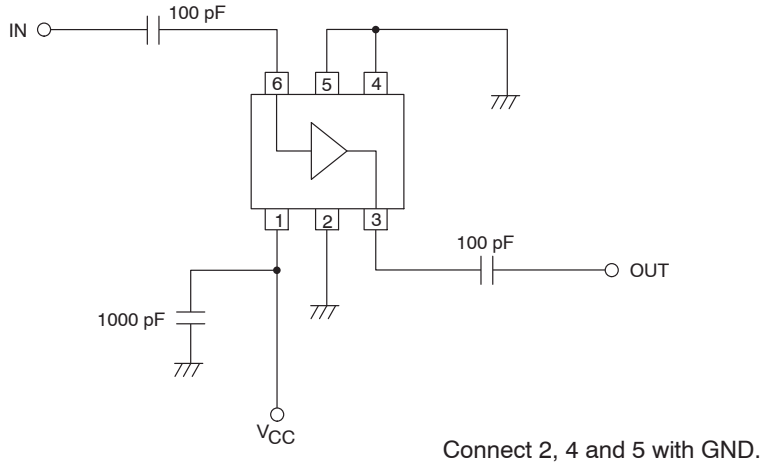
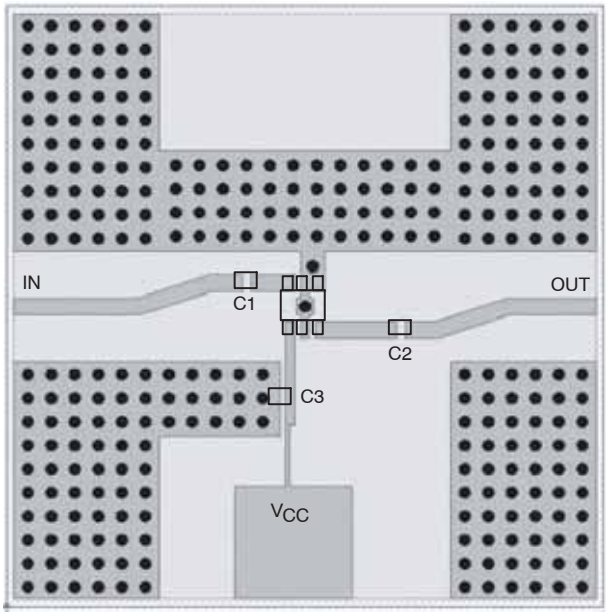


Figure 1. Test Circuit



Symbol	Value
C1, C2	100 pF
C3	1000 pF

Figure 2. Evaluation Board

TYPICAL PERFORMANCE CHARACTERISTICS

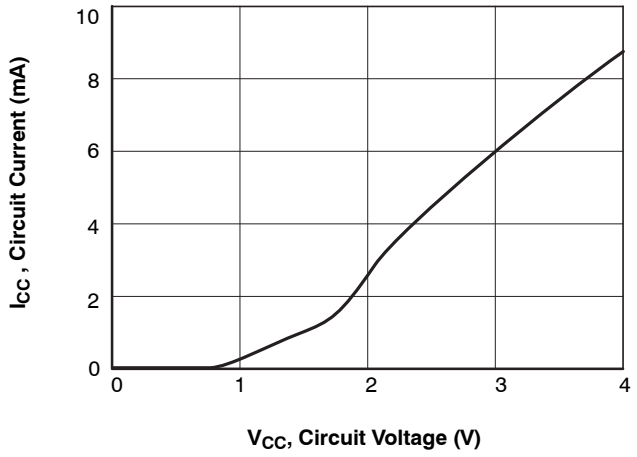


Figure 3. I_{CC} – V_{CC}

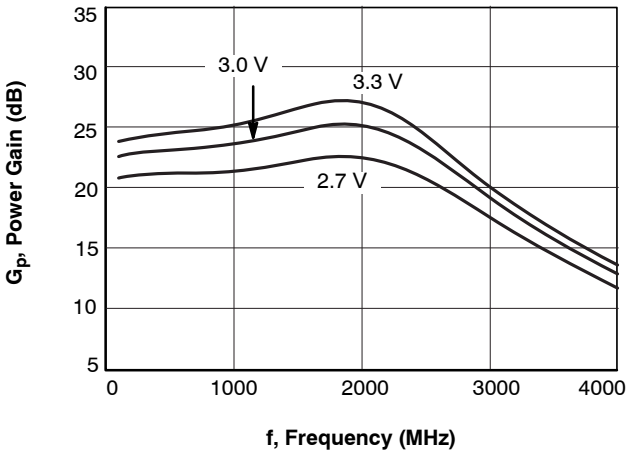


Figure 4. G_p – f

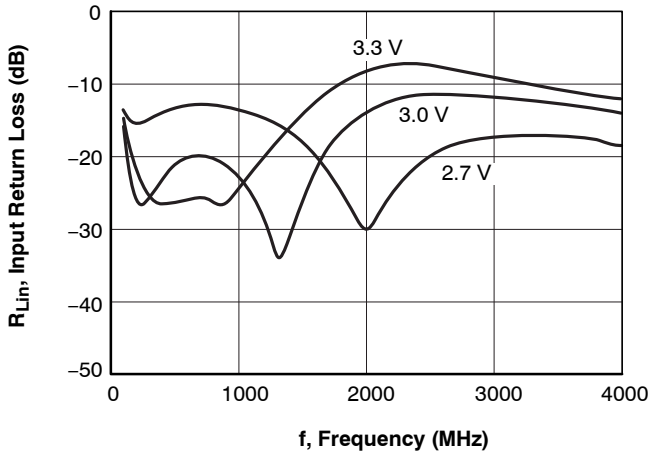


Figure 5. R_{Lin} – f

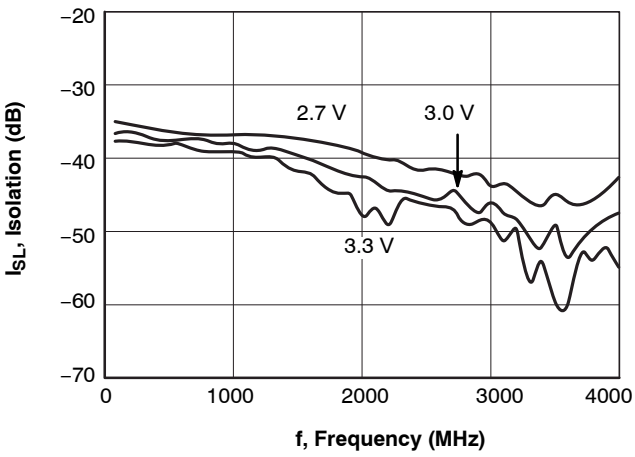


Figure 6. I_{SL} – f

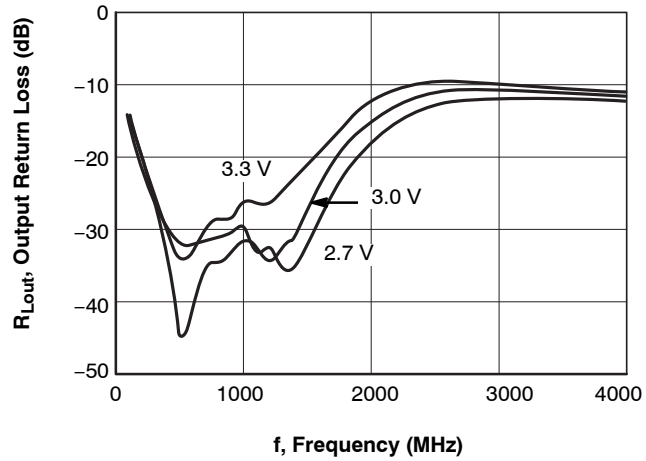


Figure 7. R_{Lout} – f

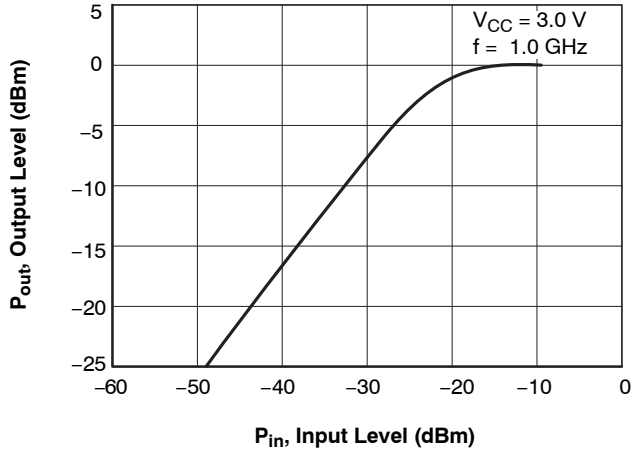


Figure 8. P_{out} – P_{in}

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

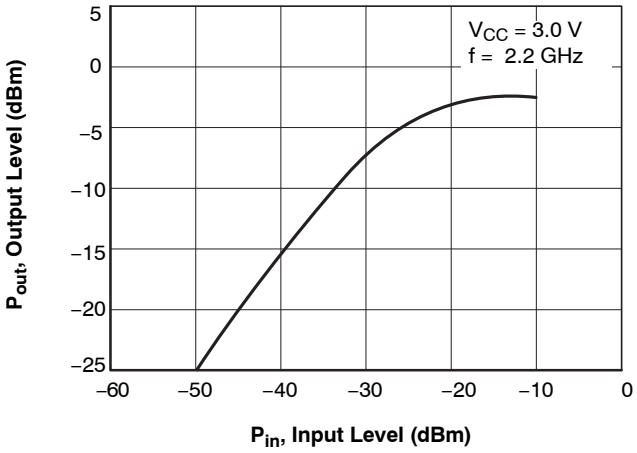


Figure 9. P_{out} − P_{in}

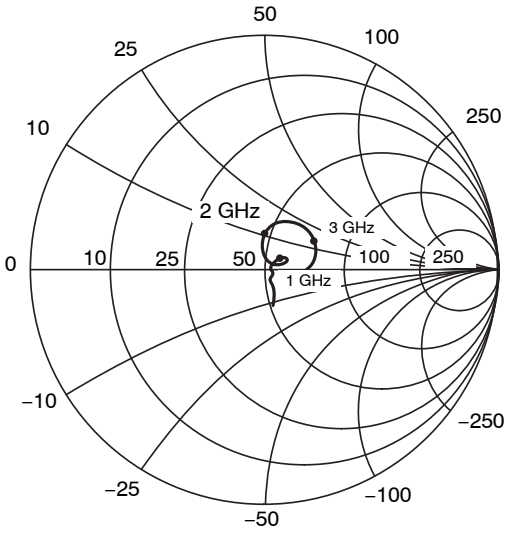


Figure 10. S Parameter, S11

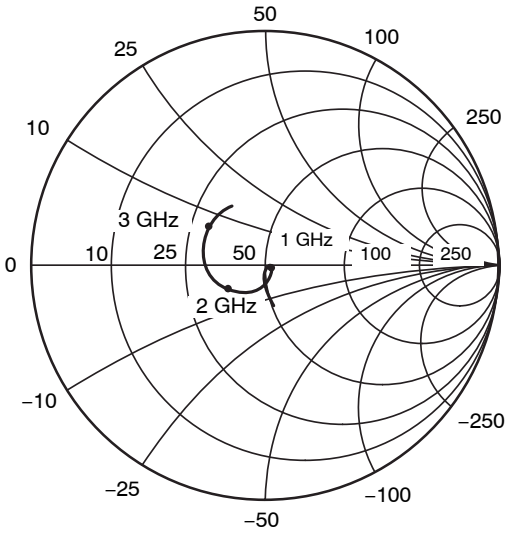
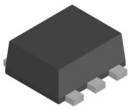
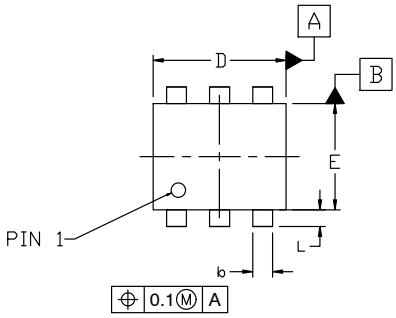


Figure 11. S Parameter, S22

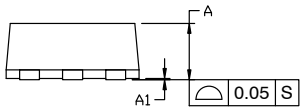


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CASE 419AS
ISSUE A

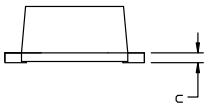
DATE 28 SEP 2022



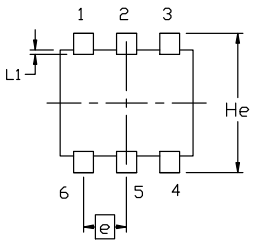
TOP VIEW



SIDE VIEW



FRONT VIEW



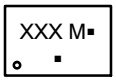
BOTTOM VIEW

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DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.80	0.85	0.90
A1	0.00	---	0.02
b	0.25	0.30	0.40
c	0.12	0.15	0.25
D	1.94	2.00	2.06
E	1.54	1.60	1.66
He	2.05	2.10	2.15
L	0.19	0.25	0.31
L1	0.00	0.07	0.12
e	0.65 BSC		

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code
M = Date Code
▪ = Pb−Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

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